## Features

- Low Insertion Loss : $0.40 \mathrm{~dB} @ 0.87 \mathrm{GHz}$
0.50 dB @ 2.5 GHz
- High Isolation: $55 \mathrm{~dB} @ 0.87 \mathrm{GHz}$

$$
47 \text { dB @ 2.5 GHz }
$$

- 50 or 75 Ohm Systems
- Low DC Power Consumption
- Miniature QFN12L (3x3 mm) Plastic Lead (Pb) Free Package
- RoHS (Restrict of Hazardous Substances) Compliant


## Description

The HWS429 is a GaAs SPDT terminated (non-reflective) switch operating at $\mathrm{DC}-3 \mathrm{GHz}$ in a low cost QFN12L ( $3 \times 3 \mathrm{~mm}$ ) plastic lead (Pb) free package. The HWS429 features low insertion loss and high isolation with very low DC power consumption and can be used in both 50 ohm and 75 ohm systems. Typical applications include CATV and basestation systems for either SPDT or SPST functions.

## QFN12L (3 x 3 mm)



Electrical Specifications at $25^{\circ} \mathrm{C}$ with $\mathbf{0 , + 3 V}$ Control Voltages, 50 Ohm system

| Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Insertion Loss | $\begin{aligned} & \mathrm{DC}-1.5 \mathrm{GHz} \\ & 1.5-3.0 \mathrm{GHz} \end{aligned}$ |  | $\begin{aligned} & 0.4 \\ & 0.5 \end{aligned}$ | 0.8 | $\begin{aligned} & \mathrm{dB} \\ & \mathrm{~dB} \end{aligned}$ |
| Isolation | $\begin{aligned} & \mathrm{DC}-1.5 \mathrm{GHz} \\ & 1.5-3.0 \mathrm{GHz} \end{aligned}$ | 35 | $\begin{aligned} & 53 \\ & 43 \end{aligned}$ |  | $\begin{aligned} & \mathrm{dB} \\ & \mathrm{~dB} \end{aligned}$ |
| Return Loss | DC-3.0 GHz |  | 15 |  | dB |
| Input Power for One dB Compression | 0.5-3.0 GHz |  | 26 |  | dBm |
| Input Third Order Intermodulation Intercept Point | 0.5-3.0 GHz |  | 45 |  | dBm |
| Switching Time |  |  | 50 |  | ns |
| Control Current |  |  | 30 | 300 | uA |

Note: All measurements made in a 50 ohm system with related application circuits and $0 /+3 \mathrm{~V}$ control voltages, unless otherwise specified.

Typical Performance Data With Application Circuit A @ + $25^{\circ} \mathrm{C}$


Isolation vs Frequency


Return Loss vs Frequency


Typical Performance Data With Application Circuit B @ $+25^{\circ} \mathrm{C}$

## Insertion Loss vs Frequency



Isolation vs Frequency


Return Loss vs Frequency


## Absolute Maximum Ratings

| Parameter | Absolute Maximum |
| :--- | :---: |
| RF Input Power | $+32 \mathrm{dBm} @+5 \mathrm{~V}$ |
| Control Voltage | +6 V |
| Operating Temperature | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| Storage Temperature | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |

## Pin Out (Top View)

Note: Circuit A and B are optimized for DC-1.5 GHz and $1.5-3.0 \mathrm{GHz}$, respectively.


Exposed pad in the bottom must be connected to ground by via holes.

## Application Circuits



Component Values:

| Circuit | C1, C2 | C3, C4 | C5, C6, C7 | C8, C9 |
| :---: | :---: | :---: | :---: | :---: |
| A | 47 pF | 330 pF | 1000 pF | 47 pF |
| B | 2 pF | 4 pF | 47 pF | 47 pF |

## Logic Table for Switch On-Path

| VC1 | VC2 | RFC-RF1 | RFC-RF2 |
| :---: | :---: | :--- | :--- |
| 0 | 1 | Insertion Loss | Isolation |
| 1 | 0 | Isolation | Insertion Loss |

$$
\begin{aligned}
& ' 1=+3 \mathrm{~V} \text { to }+5 \mathrm{~V} \\
& 0^{\prime}=0 \mathrm{~V} \text { to }+0.2 \mathrm{~V}
\end{aligned}
$$

